## YANBAN LASER

## **INFRARED DIODE LASER AT 785nm**

## RN-III-785L/1~100mW

产品描述

It features ultra compact design, long lifetime, cost-effectiveness and easy

operation. They are used in measurement, communication, spectrum analysis, etc.

产品参数

RN-III-785L/1~100mW		
Central wavelength (nm)		785±5
Operating mode		CW
Output power (mW)		> 10, 20,, 100
Power stability (rms, over 4 hours)		<1%, <2%, <3% (<0.5%, optional)
Transverse mode		Near TEM <sub>00</sub>
M <sup>2</sup> factor		~1.5
Beam diameter at the aperture (1/e <sup>2</sup> ,mm)		~4
Beam divergence, full angle (mrad)		<1
Polarization ratio		>50:1 (>100:1, optional)
		Horizontal±5 degree (Vertical Optional)
Warm-up time (minutes)		<5
Pointing stability after warm-up (mrad)		<0.05
Beam height from base plate (mm)		24.8
Operating temperature (° $\mathbb C$ )		10~35
Power supply	85-264VAC	PSU-III-LED/ PSU-III-FDA (Frequency for 1Hz-30kHz)
	100-240VAC	PSU-A-D (Frequency for 30kHz -100kHz)
TTL / Analog modulation		TTL or Analog with 1Hz-1kHz 1kHz-10kHz, 10kHz-30kHz, 30kHz-100kHz optional
Expected lifetime (hours)		10000
Warranty		1 year

北京市昌平区